

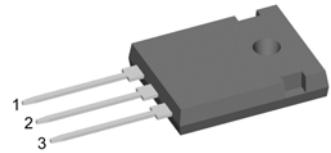
## High Efficiency Thyristor

$V_{RRM}$  = 1200V  
 $I_{TAV}$  = 30A  
 $V_T$  = 1.25V

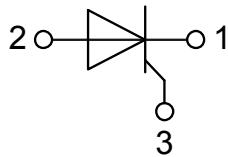
### Single Thyristor

#### Part number

CLA30E1200HB



Backside: anode



#### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

#### Applications:

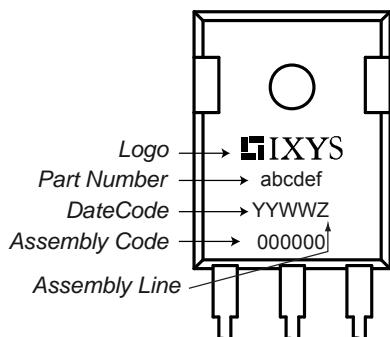
- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

#### Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Thyristor			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			1300	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			1200	V
$I_{RD}$	reverse current, drain current	$V_{RD} = 1200 \text{ V}$ $V_{RD} = 1200 \text{ V}$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		10 2	$\mu A$ mA
$V_T$	forward voltage drop	$I_T = 30 \text{ A}$ $I_T = 60 \text{ A}$ $I_T = 30 \text{ A}$ $I_T = 60 \text{ A}$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		1.28 1.56 1.25 1.61	V V V V
$I_{TAV}$	average forward current	$T_C = 120^\circ C$	$T_{VJ} = 150^\circ C$		30	A
$I_{TRMS}$	RMS forward current	180° sine			47	A
$V_{TO}$ $r_T$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 150^\circ C$		0.86 12.5	V $m\Omega$
$R_{thJC}$	thermal resistance junction to case				0.5	K/W
$R_{thCH}$	thermal resistance case to heatsink				0.25	K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ C$		250	W
$I_{TSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 \text{ V}$ $T_{VJ} = 150^\circ C$ $V_R = 0 \text{ V}$		300 325 255 275	A A
$I^2t$	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 \text{ V}$ $T_{VJ} = 150^\circ C$ $V_R = 0 \text{ V}$		450 440 325 315	$A^2s$ $A^2s$ $A^2s$ $A^2s$
$C_J$	junction capacitance	$V_R = 400 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ C$		13	pF
$P_{GM}$	max. gate power dissipation	$t_p = 30 \mu s$ $t_p = 300 \mu s$	$T_C = 150^\circ C$		10 5 0.5	W W W
$P_{GAV}$	average gate power dissipation					
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 150^\circ C; f = 50 \text{ Hz}$ repetitive, $I_T = 90 \text{ A}$ $t_p = 200 \mu s; di_G/dt = 0.3 \text{ A}/\mu s;$ $I_G = 0.3 \text{ A}; V_D = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 30 \text{ A}$			150	$A/\mu s$
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V_D = \frac{2}{3} V_{DRM}$ $R_{GK} = \infty$ ; method 1 (linear voltage rise)	$T_{VJ} = 150^\circ C$		500	$V/\mu s$
$V_{GT}$	gate trigger voltage	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		1.3 1.6	V V
$I_{GT}$	gate trigger current	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		28 50	mA mA
$V_{GD}$	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 150^\circ C$		0.2	V
$I_{GD}$	gate non-trigger current				1	mA
$I_L$	latching current	$t_p = 10 \mu s$ $I_G = 0.3 \text{ A}; di_G/dt = 0.3 \text{ A}/\mu s$	$T_{VJ} = 25^\circ C$		90	mA
$I_H$	holding current	$V_D = 6 \text{ V}$ $R_{GK} = \infty$	$T_{VJ} = 25^\circ C$		60	mA
$t_{gd}$	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$ $I_G = 0.3 \text{ A}; di_G/dt = 0.3 \text{ A}/\mu s$	$T_{VJ} = 25^\circ C$		2	$\mu s$
$t_q$	turn-off time	$V_R = 100 \text{ V}; I_T = 30 \text{ A}; V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = 150^\circ C$ $di/dt = 10 \text{ A}/\mu s; dv/dt = 20 \text{ V}/\mu s; t_p = 200 \mu s$		150		$\mu s$

Package TO-247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			50	A
$T_{stg}$	storage temperature		-55		150	°C
$T_{VJ}$	virtual junction temperature		-40		150	°C
<b>Weight</b>				6		g
$M_D$	mounting torque		0.8		1.2	Nm
$F_c$	mounting force with clip		20		120	N

**Product Marking****Part number**

C = Thyristor (SCR)  
 L = High Efficiency Thyristor  
 A = (up to 1200V)  
 30 = Current Rating [A]  
 E = Single Thyristor  
 1200 = Reverse Voltage [V]  
 HB = TO-247AD (3)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	CLA30E1200HB	CLA30E1200HB	Tube	30	508221

Similar Part	Package	Voltage class
CLA30E1200PB	TO-220AB (3)	1200
CLA30E1200PC	TO-263AB (D2Pak) (2)	1200
CS22-12io1M	TO-220ABFP (3)	1200
CS22-08io1M	TO-220ABFP (3)	800
CMA30E1600PN	TO-220ABFP (3)	1600
CMA30E1600PB	TO-220AB (3)	1600

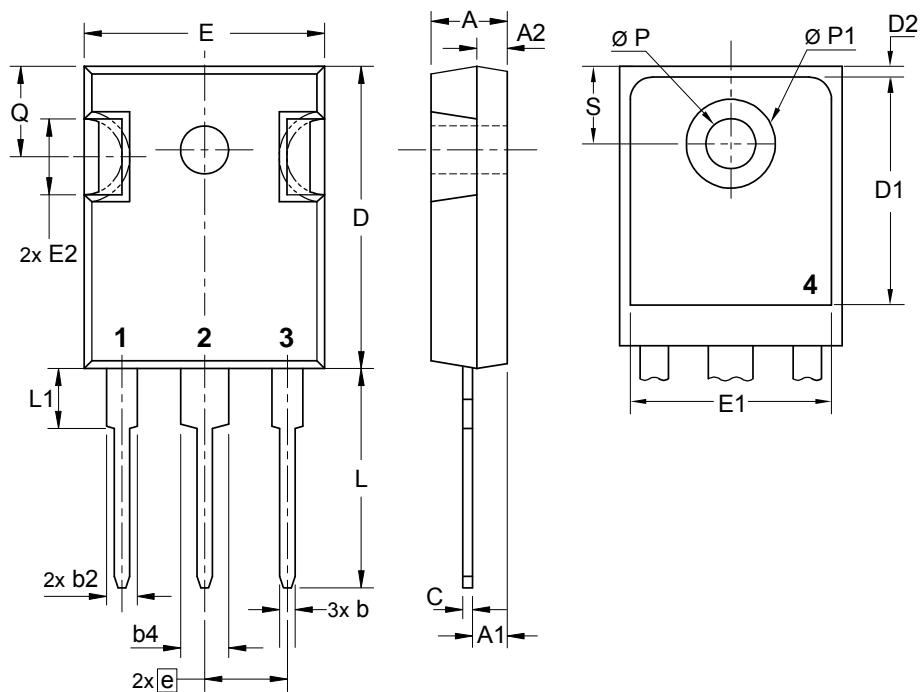
**Equivalent Circuits for Simulation**

\* on die level

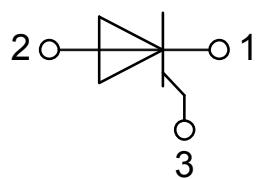
 $T_{VJ} = 150^\circ\text{C}$ 

	Thyristor
$V_{0\max}$	threshold voltage
$R_{0\max}$	slope resistance *

## Outlines TO-247



Sym.	Inches min. max.	Millimeter min. max.
A	0.185 0.209	4.70 5.30
A1	0.087 0.102	2.21 2.59
A2	0.059 0.098	1.50 2.49
D	0.819 0.845	20.79 21.45
E	0.610 0.640	15.48 16.24
E2	0.170 0.216	4.31 5.48
e	0.215 BSC	5.46 BSC
L	0.780 0.800	19.80 20.30
L1	- 0.177	- 4.49
Ø P	0.140 0.144	3.55 3.65
Q	0.212 0.244	5.38 6.19
S	0.242 BSC	6.14 BSC
b	0.039 0.055	0.99 1.40
b2	0.065 0.094	1.65 2.39
b4	0.102 0.135	2.59 3.43
c	0.015 0.035	0.38 0.89
D1	0.515 -	13.07 -
D2	0.020 0.053	0.51 1.35
E1	0.530 -	13.45 -
Ø P1	- 0.29	- 7.39



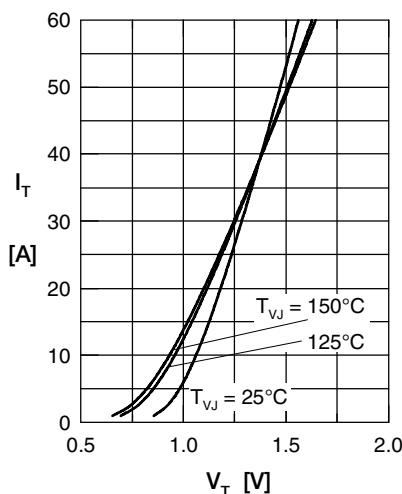
**Thyristor**

Fig. 1 Forward characteristics

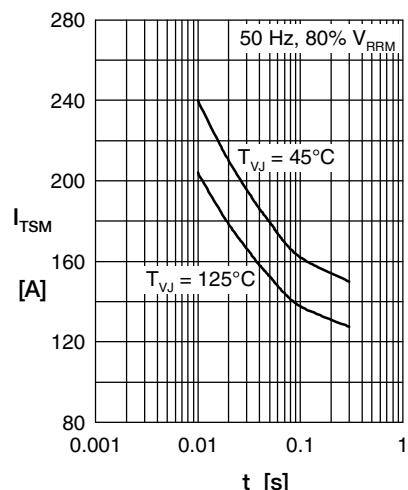
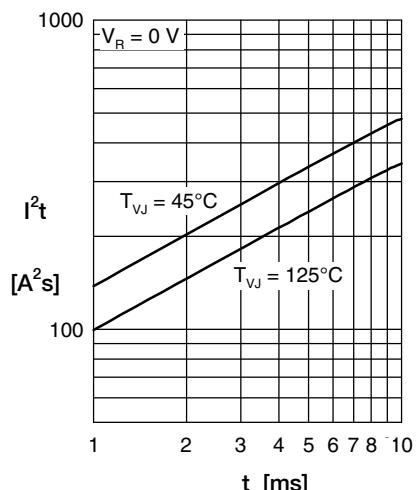
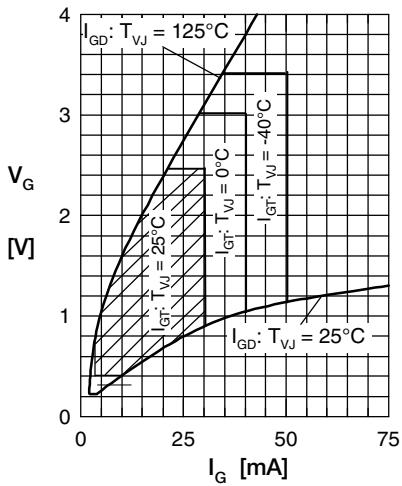
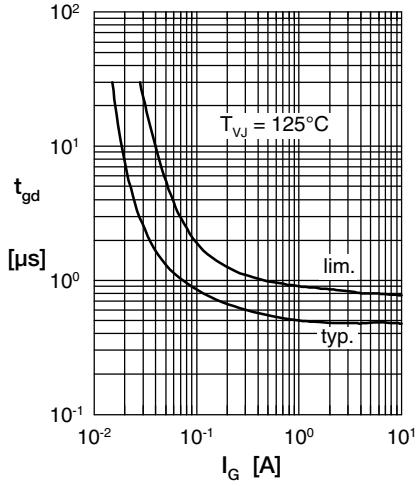
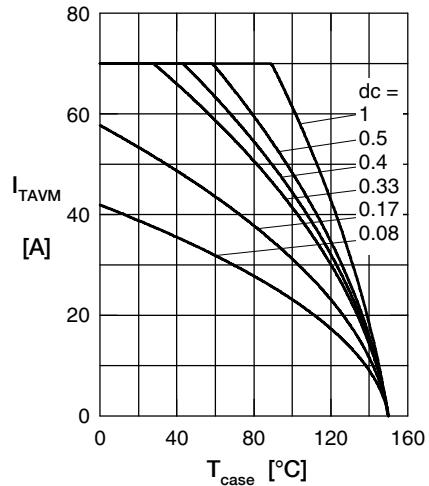
Fig. 2 Surge overload current  
 $I_{TSM}$ : crest value,  $t$ : durationFig. 3  $I^2t$  versus time (1-10 s)Fig. 4 Gate voltage & gate current  
Triggering: A = no; B = possible; C = safeFig. 5 Gate controlled delay time  $t_{gd}$ 

Fig. 6 Max. forward current at case temperature

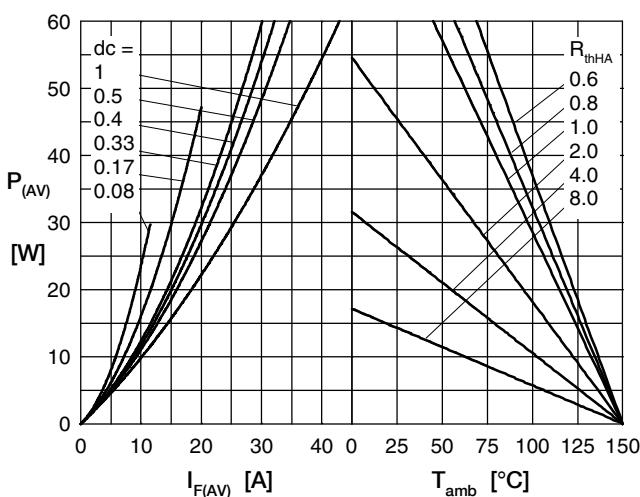
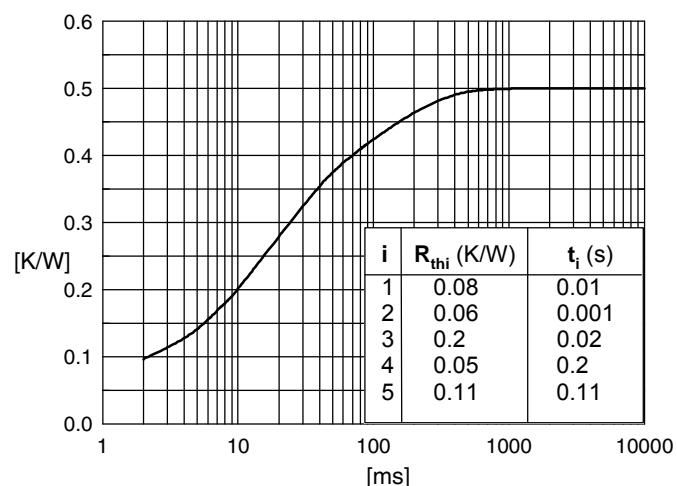
Fig. 7a Power dissipation versus direct output current  
Fig. 7b and ambient temperature

Fig. 7 Transient thermal impedance junction to case